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SOT23-3 P MOS P- CHANNEL MOSFET in a SOT23-3 Plastic Package.

$V_{DS}(V) = -30V$

$I_D = -4.2 A (V_{GS} = -10V)$

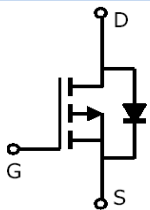
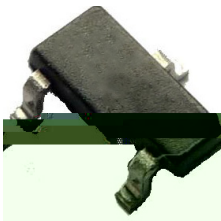
$R_{DS(ON)} < 60m\Omega (V_{GS} = -10V)$

$R_{DS(ON)} < 65m\Omega (V_{GS} = -4.5V)$

$R_{DS(ON)} < 120m\Omega (V_{GS} = -2.5V)$

Halogen free product.

This device is suitable for use as a load switch or in PWM applications.

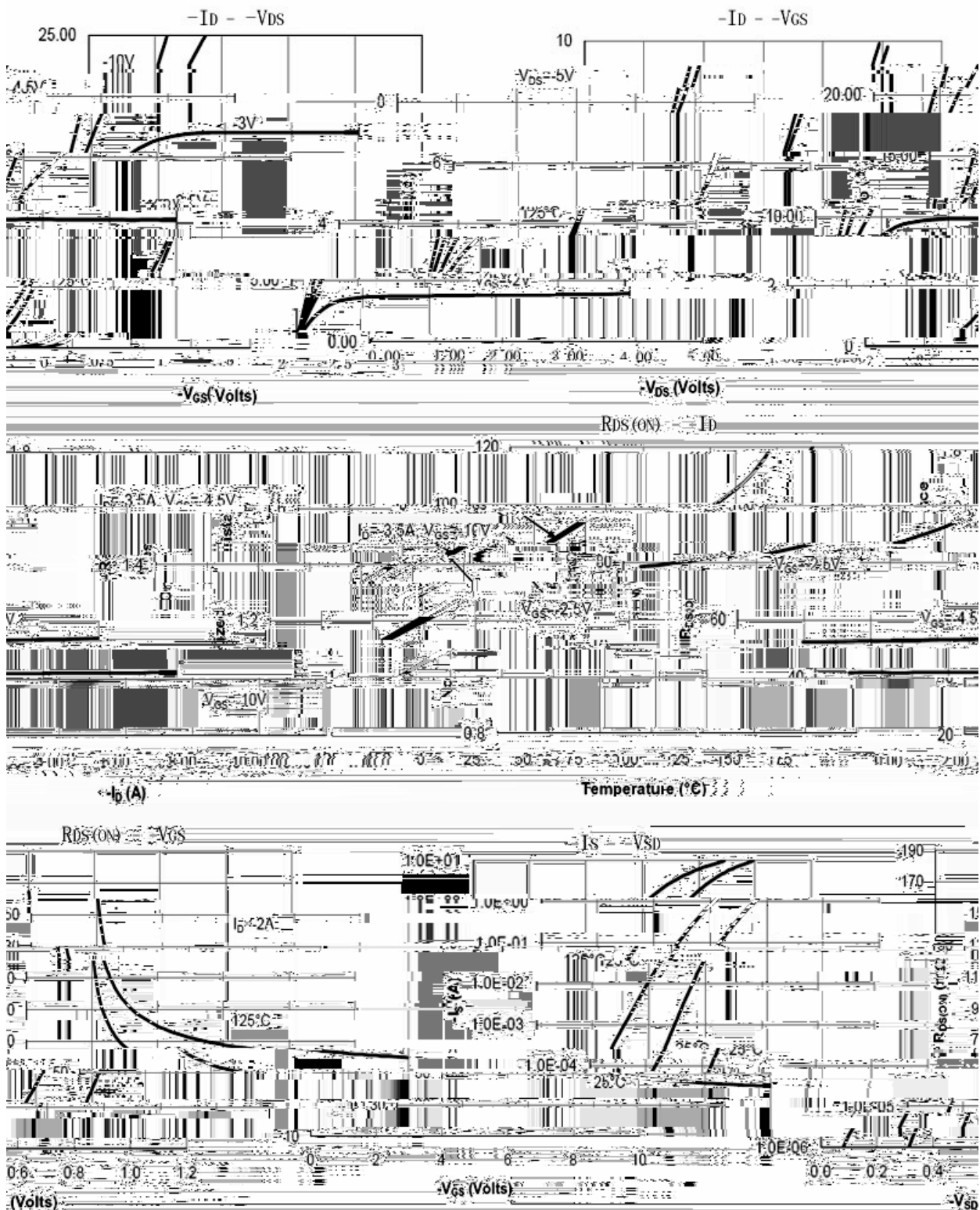


PIN1 G PIN 2 S PIN 3 D

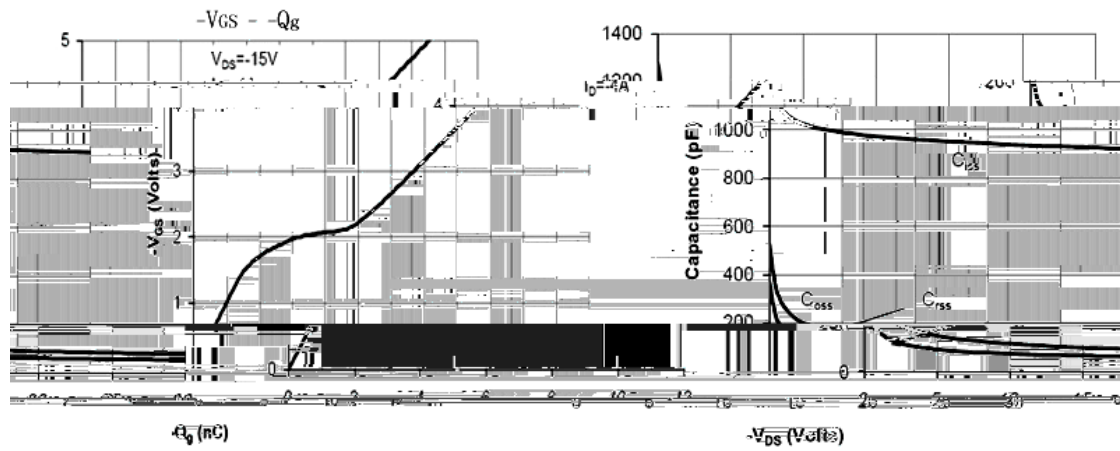
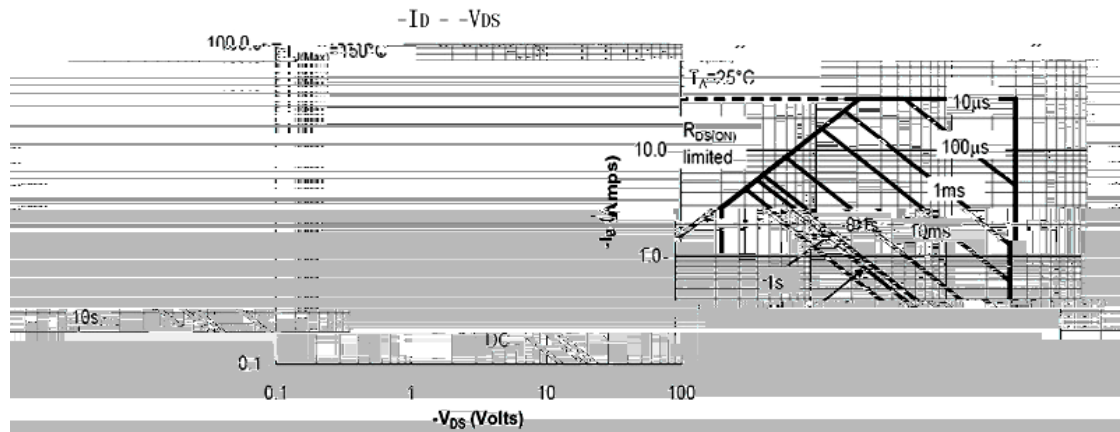
Marking	B1H
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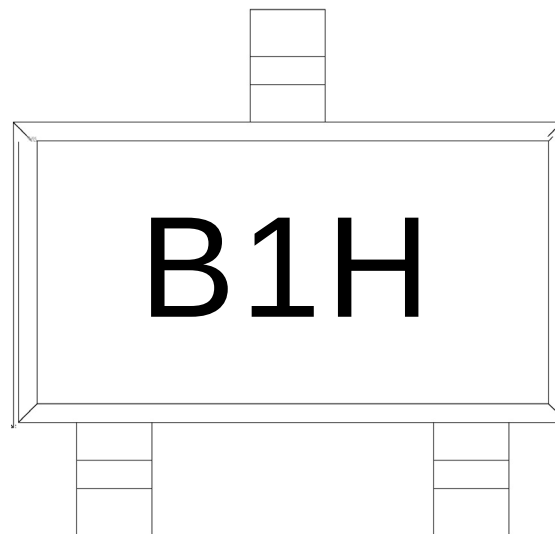
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
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B1

H

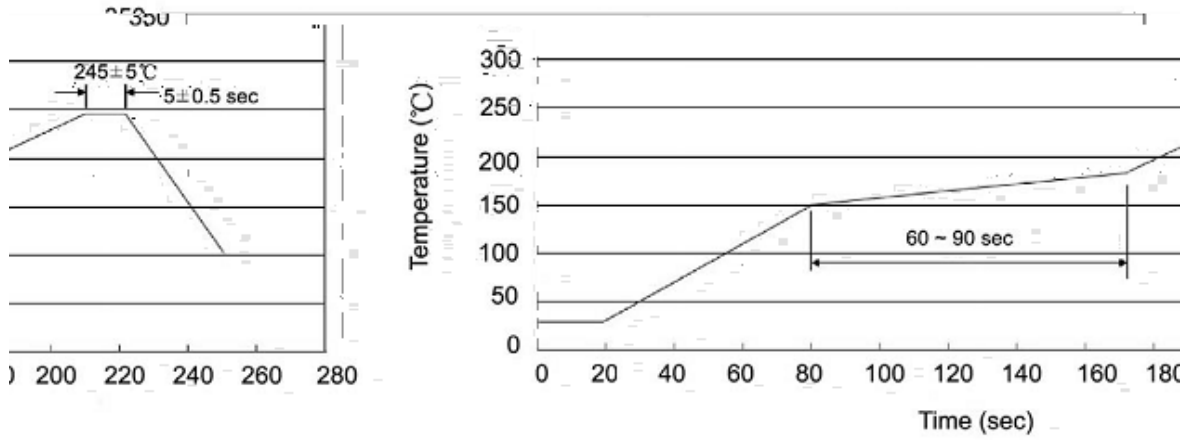
Note:

B1: Product Type Code.

H: Company Code.

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Whp shrdwxrh Prr iih i rr IU Uhi orw Vroghriq j +Pe-Frhh,



Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 150 | 180 | 60 | 90sec; | 1.Preheating:150~180 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

260±5

10±1 sec.

Temp.:260±5

Time:10±1 sec

/ REEL